

## SLOVENSKI STANDARD oSIST prEN IEC 63550-1:2025

01-november-2025

Polprevodniški elementi - Nevromorfne naprave - 1. del: Metoda ocenjevanja osnovnih značilnosti v memristorskih napravah

Semiconductor devices - Neuromorphic devices - Part 1: Evaluation method of basic characteristics in memristor devices

iTeh Standards

Dispositifs à semiconducteurs - Dispositifs neuromorphiques - Partie 1: Méthode d'évaluation des caractéristiques de base des dispositifs à memristance

Ta slovenski standard je istoveten z: prEN IEC 63550-1:2025

ICS:

31.080.99 Drugi polprevodniški elementi Other semiconductor devices

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## iTeh Standards (https://standards.iteh.ai) Document Preview

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SUPERSEDES DOCUMENTS:



## 47/2943/CDV

## COMMITTEE DRAFT FOR VOTE (CDV)

CLOSING DATE FOR VOTING:

2025-11-28

47/2870/CD, 47/2925/CC		
IEC TC 47 : SEMICONDUCTOR DEVICES		
SECRETARIAT:	SECRETARY:	
Korea, Republic of	Mr Cheolung Cha	
OF INTEREST TO THE FOLLOWING COMMITTEES:	HORIZONTAL FUNCTION(S):	
ASPECTS CONCERNED:		
SUBMITTED FOR CENELEC PARALLEL VOTING	☐ NOT SUBMITTED FOR CENELEC PARALLEL VOTING	
Attention IEC-CENELEC parallel voting	andards	
The attention of IEC National Committees, members of CENELEC, is drawn to the fact that this Committee Draft for Vote (CDV) is submitted for parallel voting.	lards.iteh.ai)	
The CENELEC members are invited to vote through the CENELEC online voting system.	t Preview	
This document is still under study and subject to change	501_1601_9d82_de0bdfac1370/osist_prep_iec_635	
Recipients of this document are invited to submit, with the which they are aware and to provide supporting documents.	eir comments, notification of any relevant patent rights of ntation.	
	n their comments, notification of any relevant "In Some proceed. Recipients are reminded that the CDV stage is 07 OR NEW GUIDANCE DOC).	
TITLE:		
Semiconductor devices - Neuromorphic de characteristics in memristor devices	vices - Part 1: Evaluation method of basic	
PROPOSED STABILITY DATE: 2029		
NOTE FROM TC/SC OFFICERS:		

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